## NSN 5962-01-214-5320

Memory Microcircuit - Page 1 of 1



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Body Length:         1.200 inches         Body Width:         0.295 inches         Body Height:         0.120 inches         Maximum Power Dissipation Rating:         1.10 watts         Operating Tempurature Range:         -55.0 to 125.0 degrees celsius         Storage Tempurature Range:         -65.0 to 150.0 degrees celsius         Features Provided:         Hermetically sealed and monolithic and low power         Inclosure Material:         Ceramic         Inclosure Configuration:         Dual-in-line         Output Logic Form:         Complementary-metal oxide-semiconductor logic         Input Crucit Pattern:         16 input         Solder         Voltage Rating And Type Per Characteristic:         Solder         Voltage Rating And Type Per Characteristic:         Solder         Brow poweris-dated (includes industry or association standards, individual manufactureer standards, etc.).         Terminal Type And Quantity:         24 printed circuit
Body Width:         0.295 inches         Body Height:         0.120 inches         Maximum Power Dissipation Rating:         1.0 watts         Operating Tempurature Range:         -55.0 to 125.0 degrees celsius         Storage Tempurature Range:         -55.0 to 50.0 degrees celsius         Features Provided:         Hernetically sealed and monolithic and low power         Inclosure Material:         Ceramic         Dual-inline         Output Logic Form:         Complementary-metal oxide-semiconductor logic         Input Circuit Pattern:         Solder         Voltage Rating And Type Per Characteristic:         S.5 volts power source         Memory Device Type:         Ram         Testaba Document:         9600-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).         Terminal Type And Quantity:         24 printed circuit         Shoft Life:         Na
0.29         Body Height:         0.120 inches         Maximum Power Dissipation Rating:         1.0 watts         Operating Tempurature Range:         :55.0 to 125.0 degrees celsius         Storage Tempurature Range:         :65.0 to 125.0 degrees celsius         Pertures Provided:         Hermetically sealed and monolithic and low power         Inclosure Material:         Ceramic         Dual-in-line         Output Logic Form:         Complementary-metal oxide-semiconductor logic         Input Cricuit Pattern:         16 input         Yolage Rating And Type Per Characteristic:         Sto Yolsp power source         Memory Device Type:         Ram         Casolo Cocument:         9000-mil-std-83 standard (includes industry or association standards, individual manufactureer standards, etc.).         Terminal Type And Quantity:         24 printed circuit         Shelf Life:         Na
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Input Circuit Pattern:16 input16 inputTerminal Surface Treatment:SolderVoltage Rating And Type Per Characteristic:5.5 volts power sourceMemory Device Type:RamTest Data Document:96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).Terminal Type And Quantity:24 printed circuitShelf Life:N/a
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24 printed circuit Shelf Life: N/a
Shelf Life: N/a
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
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